

**30A, 400V - 600V Hyperfast Diodes**

The RHRG3040 and RHRG3060 are hyperfast diodes with soft recovery characteristics ( $t_{rr} < 40ns$ ). They have half the recovery time of ultrafast diodes and are of silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49063.

**Ordering Information**

PART NUMBER	PACKAGE	BRAND
RHRG3040	TO-247	RHRG3040
RHRG3060	TO-247	RHRG3060

NOTE: When ordering, use the entire part number.

**Symbol**



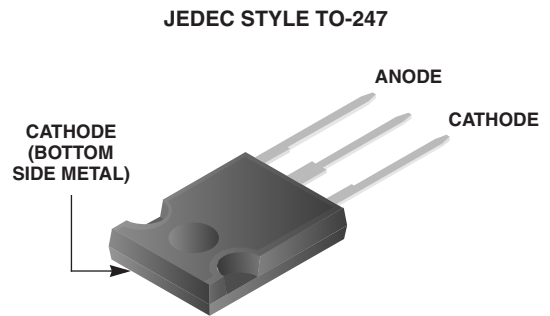
**Features**

- Hyperfast with Soft Recovery . . . . . <40ns
- Operating Temperature . . . . . 175°C
- Reverse Voltage Up To . . . . . 600V
- Avalanche Energy Rated
- Planar Construction

**Applications**

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

**Packaging**



**Absolute Maximum Ratings**  $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	RHRG3040	RHRG3060	UNITS
Peak Repetitive Reverse Voltage . . . . . $V_{RRM}$	400	600	V
Working Peak Reverse Voltage . . . . . $V_{RWM}$	400	600	V
DC Blocking Voltage . . . . . $V_R$	400	600	V
Average Rectified Forward Current . . . . . $I_{F(AV)}$ ( $T_C = 120^{\circ}C$ )	30	30	A
Repetitive Peak Surge Current . . . . . $I_{FRM}$ (Square Wave, 20kHz)	70	70	A
Nonrepetitive Peak Surge Current . . . . . $I_{FSM}$ (Halfwave, 1 Phase, 60Hz)	325	325	A
Maximum Power Dissipation . . . . . $P_D$	125	125	W
Avalanche Energy (See Figures 10 and 11) . . . . . $E_{AVL}$	20	20	mJ
Operating and Storage Temperature . . . . . $T_{STG}, T_J$	-65 to 175	-65 to 175	°C

# RHRG3040, RHRG3060

## Electrical Specifications $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	RHRG3040			RHRG3060			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
$V_F$	$I_F = 30\text{A}$	-	-	2.1	-	-	2.1	V
	$I_F = 30\text{A}, T_C = 150^\circ\text{C}$	-	-	1.7	-	-	1.7	V
$I_R$	$V_R = 400\text{V}$	-	-	250	-	-	-	$\mu\text{A}$
	$V_R = 600\text{V}$	-	-	-	-	-	250	$\mu\text{A}$
	$V_R = 400\text{V}, T_C = 150^\circ\text{C}$	-	-	1.0	-	-	-	mA
	$V_R = 600\text{V}, T_C = 150^\circ\text{C}$	-	-	-	-	-	1.0	mA
$t_{rr}$	$I_F = 1\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	-	-	40	-	-	40	ns
	$I_F = 30\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	-	-	45	-	-	45	ns
$t_a$	$I_F = 30\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	-	22	-	-	22	-	ns
$t_b$	$I_F = 30\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	-	18	-	-	18	-	ns
$Q_{RR}$	$I_F = 30\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$	-	100	-	-	100	-	nC
$C_J$	$V_R = 10\text{V}, I_F = 0\text{A}$	-	85	-	-	85	-	pF
$R_{\theta JC}$		-	-	1.2	-	-	1.2	$^\circ\text{C}/\text{W}$

### DEFINITIONS

$V_F$  = Instantaneous forward voltage ( $pw = 300\mu\text{s}$ ,  $D = 2\%$ ).

$I_R$  = Instantaneous reverse current.

$t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a + t_b$ .

$t_a$  = Time to reach peak reverse current (See Figure 9).

$t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).

$Q_{RR}$  = Reverse recovery charge.

$C_J$  = Junction Capacitance.

$R_{\theta JC}$  = Thermal resistance junction to case.

$pw$  = Pulse width.

$D$  = Duty cycle.

## Typical Performance Curves

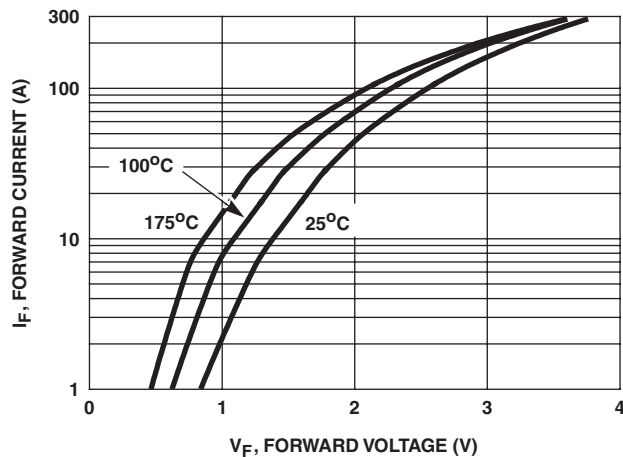


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

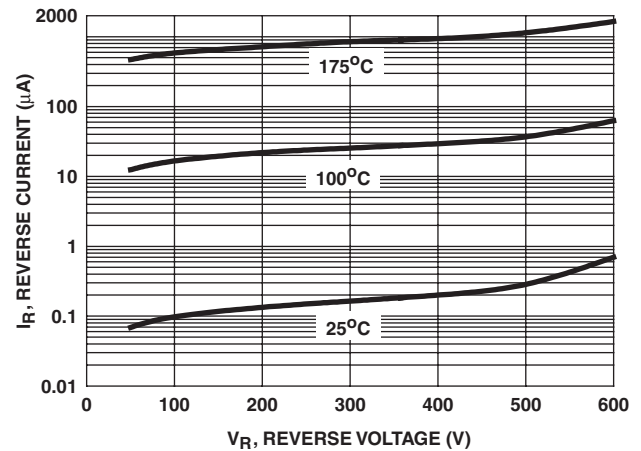


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

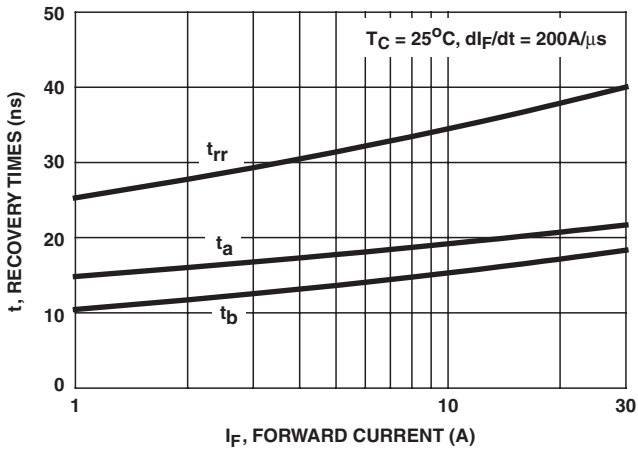


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

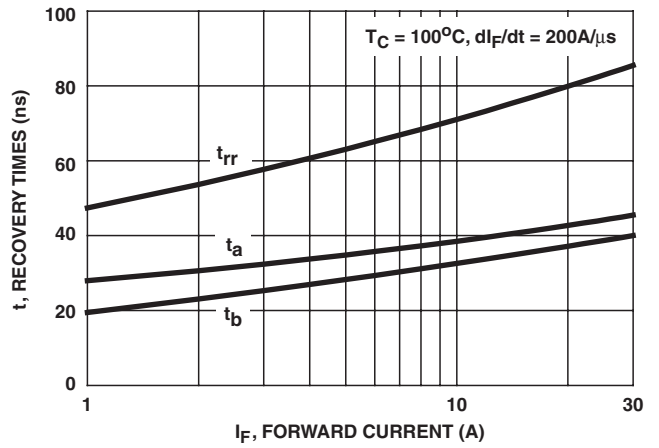


FIGURE 4.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

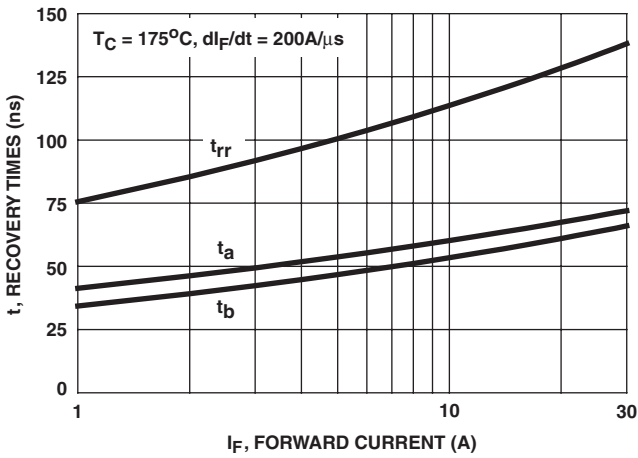


FIGURE 5.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

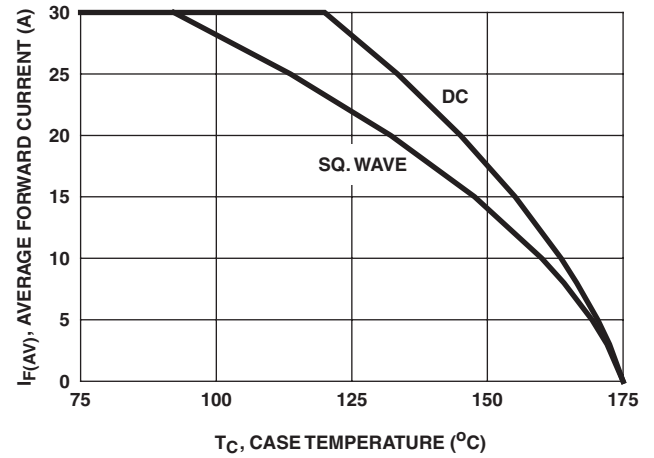


FIGURE 6. CURRENT DERATING CURVE

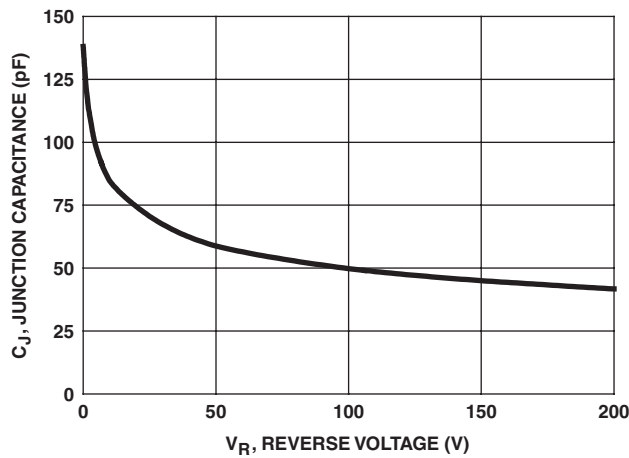


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

**Test Circuits and Waveforms**

$V_{GE}$  AMPLITUDE AND  
 $R_G$  CONTROL  $di_F/dt$   
 $t_1$  AND  $t_2$  CONTROL  $I_F$

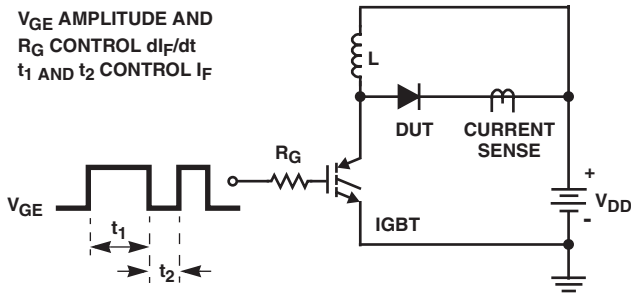


FIGURE 8.  $t_{rr}$  TEST CIRCUIT

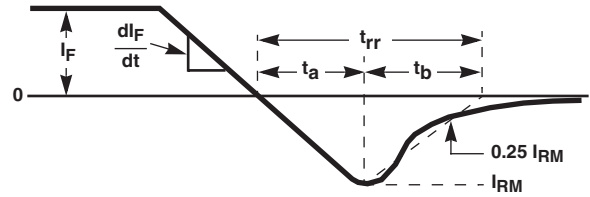


FIGURE 9.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

$I_{MAX} = 1A$   
 $L = 40mH$   
 $R < 0.1\Omega$   
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$   
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

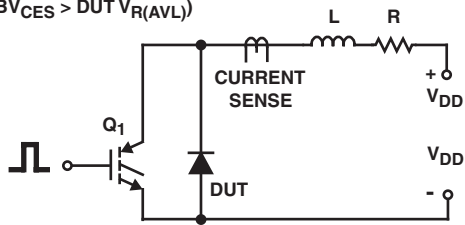


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

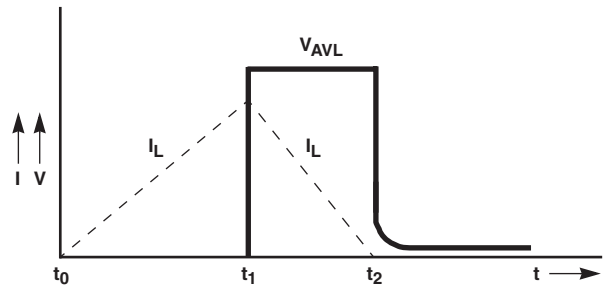


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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FACT™	MicroPak™	Quiet Series™	UHC™	
FACT Quiet Series™	MICROWIRE™	SILENT SWITCHER®	UltraFET®	

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